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	Complete if Known	
Application Number	Div. 0f 09/667,610	1
Filing Date	Herewith	٥
First Named Inventor	Ken Takeuchi et al.	à
Group Art Unit	2818	U
Examiner Name	Н. Но	
Attorney Docket Number	001701.00140	

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Examiner Initials *	Cite No.1	Document Number	Publication D			Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
		Number - Kind Code ² (if known)	MM-DD-YY				
MA		US-6134140	10/2000		Tanaka et al.		
pm		US-6055181	4/2000		Tanaka et al.		
1000		US-5870334	2/1999		Hemink et al.	,	
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m		Tae-Sung JUNG et al., "A 3.3V 128Mb Multi-Level NAND Flash Memory for Mass Storage Applications", 1996 IEEE International Solid-State Circuits Conference, pages 32-33.	*
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